Hex buffer/line driver; 3-state; inverting Rev. 5 — 2 February 2016

General description 1.

The 74HC366; 74HCT366 is a hex inverting buffer/line driver with 3-state outputs controlled by the output enable inputs (OEn). A HIGH on OEn causes the outputs to assume a high impedance OFF-state. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

Features and benefits 2.

- Inverting outputs
- Input levels:
 - For 74HC366: CMOS level
 - For 74HC366: TTL level
- Complies with JEDEC standard no. 7A
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Specified from –40 °C to +85 °C and from –40 °C to +125 °C
- Multiple package options

Ordering information 3.

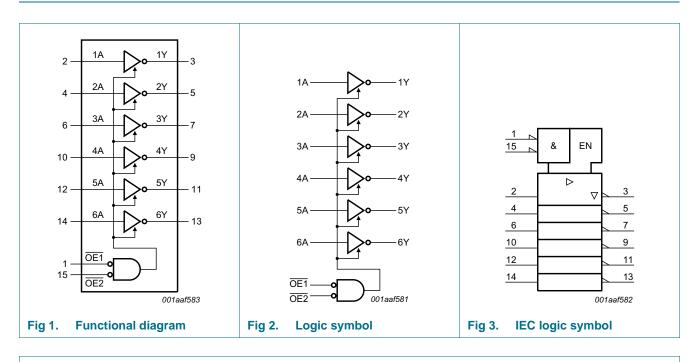
Table 1. **Ordering information**

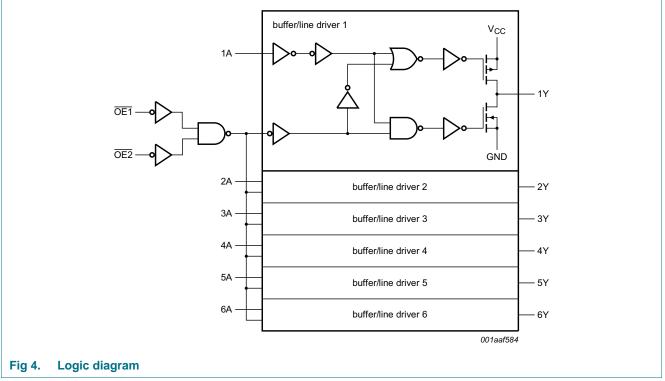
Type number	Package			
	Temperature range	Name	Description	Version
74HC366				
74HC366D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HC366PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74HCT366				
74HCT366D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HCT366DB	–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1
74HCT366PW	−40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1

nexperia

Hex buffer/line driver; 3-state; inverting

4. Functional diagram



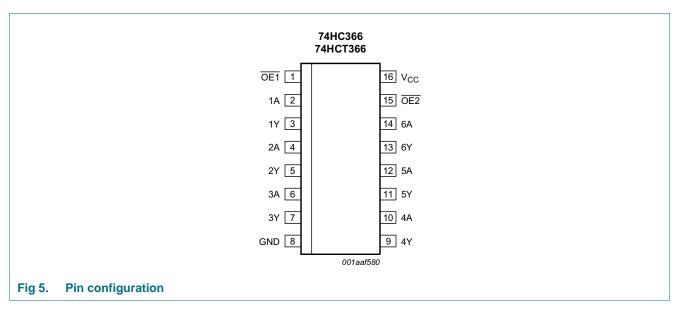


Product data sheet

Hex buffer/line driver; 3-state; inverting

5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
OE1, OE2	1, 15	output enable input (active LOW)
1A, 2A, 3A, 4A, 5A, 6A	2, 4, 6, 10, 12, 14	data input
1Y, 2Y, 3Y, 4Y, 5Y, 6Y	3, 5, 7, 9, 11, 13	data output
GND	8	ground (0 V)
V _{CC}	16	supply voltage

6. Functional description

Table 3. Function table^[1]

		Input	Output
OE1	OE2	nA	nY
L	L	L	Н
L	L	Н	L
Х	Н	Х	Z
Н	Х	Х	Z

[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care;

Z = high-impedance OFF-state.

Hex buffer/line driver; 3-state; inverting

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _{OK}	output clamping current	$V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	-	±20	mA
lo	output current	$V_{O} = -0.5 \text{ V to} (V_{CC} + 0.5 \text{ V})$	-	±35	mA
I _{CC}	supply current		-	70	mA
I _{GND}	ground current		-	-70	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	SO16 package	-	500	mW
		SSOP16 package [2]	-	500	mW
		TSSOP16 package [2]	-	500	mW

[1] For SO16 packages: P_{tot} derates linearly with 8 mW/K above 70 °C.

[2] For SSOP16 and TSSOP16 packages: P_{tot} derates linearly with 5.5 mW/K above 60 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions		74HC366	5	7	4HCT36	6	Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 2.0 V$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5 V$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 V$	-	-	83	-	-	-	ns/V

Hex buffer/line driver; 3-state; inverting

9. Static characteristics

Table 6. Static characteristics 74HC366

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

T _{amb} = 2 V _{IH}	25 °C HIGH-level input voltage					
V _{IH}	HIGH-level input voltage					
	i iiGi i-level iliput voltage	V _{CC} = 2.0 V	1.5	1.2	-	V
		V _{CC} = 4.5 V	3.15	2.4	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	V
VIL	LOW-level input voltage	V _{CC} = 2.0 V	-	0.8	0.5	V
		V _{CC} = 4.5 V	-	2.1	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}	-	-	-	
		$I_0 = -20 \ \mu\text{A}; \ V_{CC} = 2.0 \ \text{V}$	1.9	2.0	-	V
		$I_{O} = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	4.5	- 0.5 1.35 1.8 - - - - - - - - - - - - -	V
		$I_0 = -20 \ \mu\text{A}; \ V_{CC} = 6.0 \ \text{V}$	5.9	6.0		V
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	V
		$I_{O} = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		$I_0 = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	0	0.1	V
		$I_0 = 20 \ \mu A; V_{CC} = 4.5 \ V$	-	0	0.1	V
		$I_0 = 20 \ \mu A; V_{CC} = 6.0 \ V$	-	0 0.4	0.1	V
		$I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	V
		I _O = 7.8 mA; V _{CC} = 6.0 V	-	0.16	0.26	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±0.1	μA
l _{oz}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or } \text{GND}; V_{CC} = 6.0 \text{ V}$	-	-	±0.5	μA
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	8.0	μA
CI	input capacitance		-	3.5	-	pF
T _{amb} = -	-40 °C to +85 °C	1				
VIH	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
VIL	LOW-level input voltage	V _{CC} = 2.0 V	-	-	1.35 1.8 - - - - - - 0.1 0.1 0.1 0.26 0.26 ±0.1 ±0.5 8.0 - - - - - - - - - - - - -	V
		V _{CC} = 4.5 V	-	-		V
		V _{CC} = 6.0 V	-	-	1.8	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_0 = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	-	-	V
		$I_0 = -20 \ \mu A; \ V_{CC} = 4.5 \ V$	4.4	-	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	-	-	V
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.84	-	-	V
		I _O = -7.8 mA; V _{CC} = 6.0 V	5.34	-	-	V

Hex buffer/line driver; 3-state; inverting

Table 6. Static characteristics 74HC366 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		$I_0 = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	-	0.1	V
		$I_0 = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	-	0.1	V
		$I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.33	V
		I _O = 7.8 mA; V _{CC} = 6.0 V	-	-	0.33	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0$ V;	-	-	±1.0	μA
l _{oz}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or } \text{GND}; V_{CC} = 6.0 \text{ V}$	-	-	±5.0	μA
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	80	μA
T _{amb} = -	40 °C to +125 °C	·				<u>.</u>
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		$I_0 = -20 \ \mu\text{A}; \ V_{CC} = 2.0 \ \text{V}$	1.9	-	-	V
		$I_0 = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	-	-	V
		$I_0 = -20 \ \mu\text{A}; \ V_{CC} = 6.0 \ \text{V}$	5.9	-	-	V
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	V
		$I_0 = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.2	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		$I_0 = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	-	0.1	V
		$I_0 = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	-	0.1	V
		I _O = 6.0 mA; V _{CC} = 4.5 V	-	-	0.4	V
		$I_0 = 7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.4	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH}$ or V_{IL} ; $V_{O} = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±10.0	μA
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	160	μA

Hex buffer/line driver; 3-state; inverting

Table 7. Static characteristics 74HCT366

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	25 °C					_
VIH	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	1.6	-	V
VIL	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	1.2	0.8	V
V _{OH}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = -20 μA	4.4	4.5	-	V
		I _O = -6.0 mA	3.98	4.32	-	V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = 20 μA	-	0	0.1	V
		I _O = 6.0 mA	-	0.16	0.26	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±0.1	μA
l _{oz}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or GND}; V_{CC} = 5.5 \text{ V}$	-	-	±0.5	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	8.0	μA
ΔI_{CC}	additional supply current	$V_I = V_{CC} - 2.1$ V; other inputs at V_{CC} or GND; $I_O = 0$ A				
		pins nA	-	100	360	μA
		pin OE1	-	100	360	μA
		pin OE2	-	90	320	μA
CI	input capacitance		-	3.5	-	pF
T _{amb} = -	-40 °C to +85 °C					_
VIH	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	-	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	0.8	V
V _{OH}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = -20 μA	4.4	-	-	V
		I _O = -6.0 mA	3.84	-	-	V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = 20 μA	-	-	0.1	V
		I _O = 6.0 mA	-	-	0.33	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±1.0	μA
l _{oz}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or GND}; V_{CC} = 5.5 \text{ V}$			±5.0	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	80	μA
ΔI_{CC}	additional supply current	$V_I = V_{CC} - 2.1$ V; other inputs at V_{CC} or GND; $I_O = 0$ A				
		pins nA	-	-	450	μA
		pin OE1	-	-	450	μA
		pin OE2	-	-	400	μA

Hex buffer/line driver; 3-state; inverting

Table 7. Static characteristics 74HCT366 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -	40 °C to +125 °C					
V _{IH}	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	-	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	0.8	V
V _{OH}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = -20 μA	4.4	-	-	V
		$I_{\rm O} = -6.0 \rm{mA}$	3.7	-	-	V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = 20 μA	-	-	0.1	V
		I _O = 6.0 mA	-	-	0.4	V
I _I	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±1.0	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or GND}; V_{CC} = 5.5 \text{ V}$	-	-	±10.0	μA
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 5.5$ V	-	-	160	μA
ΔI_{CC}	additional supply current	$V_I = V_{CC} - 2.1$ V; other inputs at V_{CC} or GND; $I_O = 0$ A				
		pins nA	-	-	490	μA
		pin OE1	-	-	490	μA
		pin OE2	-	-	441	μA

10. Dynamic characteristics

Table 8. Dynamic characteristics 74HC366

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; see test circuit Figure 8.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = 2	5 °C			1	•	1	-1
t _{pd}	propagation delay	nA to nY; see Figure 6	<u>[1]</u>				
		V _{CC} = 2.0 V		-	33	100	ns
		V _{CC} = 4.5 V		-	12	20	ns
		V _{CC} = 5 V; C _L = 15 pF		-	10	-	ns
		V _{CC} = 6.0 V		-	10	17	ns
t _{en}	enable time	OEn to nY; see Figure 7	[2]				
		V _{CC} = 2.0 V		-	44	150	ns
		V _{CC} = 4.5 V		-	16	30	ns
		V _{CC} = 6.0 V		-	13	26	ns
t _{dis}	disable time	OEn to nY; see Figure 7	[3]				
		V _{CC} = 2.0 V		-	55	150	ns
		V _{CC} = 4.5 V		-	20	30	ns
		V _{CC} = 6.0 V		-	16	26	ns
t _t	transition time	see <u>Figure 6</u>	<u>[4]</u>				
		V _{CC} = 2.0 V		-	14	60	ns
		V _{CC} = 4.5 V		-	5	12	ns
		V _{CC} = 6.0 V		-	4	10	ns

Hex buffer/line driver; 3-state; inverting

Table 8. Dynamic characteristics 74HC366 ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; see test circuit Figure 8.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
C _{PD}	power dissipation capacitance	per buffer; $V_I = GND$ to V_{CC}	[5]	-	30	-	pF
T _{amb} = -	40 °C to +85 °C	'					_
t _{pd}	propagation delay	nA to nY; see Figure 6	<u>[1]</u>				
		V _{CC} = 2.0 V		-	-	125	ns
		V _{CC} = 4.5 V		-	-	25	ns
		V _{CC} = 6.0 V		-	-	21	ns
t _{en}	enable time	OEn to nY; see Figure 7	[2]				
		V _{CC} = 2.0 V		-	-	190	ns
		V _{CC} = 4.5 V		-	-	38 33 190 38 33	ns
		V _{CC} = 6.0 V		-	-		ns
t _{dis}	disable time	OEn to nY; see Figure 7	[3]				
		V _{CC} = 2.0 V		-	-	190	ns
		V _{CC} = 4.5 V		-	-	38	ns
		V _{CC} = 6.0 V		-	-	33	ns
t _t	transition time	see <u>Figure 6</u>	<u>[4]</u>			75	
		V _{CC} = 2.0 V		-	-		ns
		V _{CC} = 4.5 V		-	-	15	ns
		V _{CC} = 6.0 V		-	-	13	ns
T _{amb} = -	40 °C to +125 °C						_
t _{pd}	propagation delay	nA to nY; see <u>Figure 6</u>	<u>[1]</u>				
		V _{CC} = 2.0 V		-	-	150	ns
		V _{CC} = 4.5 V		-	-	30	ns
		V _{CC} = 6.0 V		-	-	26	ns
t _{en}	enable time	OEn to nY; see Figure 7	[2]				
		V _{CC} = 2.0 V		-	-	225	ns
		V _{CC} = 4.5 V		-	-	45	ns
		V _{CC} = 6.0 V		-	-	38	ns
t _{dis}	disable time	OEn to nY; see Figure 7	[3]				
		V _{CC} = 2.0 V		-	-	225	ns
		V _{CC} = 4.5 V		-	-	45	ns
		$V_{CC} = 6.0 V$		-	-	38	ns

Hex buffer/line driver; 3-state; inverting

Table 8. Dynamic characteristics 74HC366 ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; see test circuit Figure 8.

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
t _t	transition time	see Figure 6 [4]				
		$V_{CC} = 2.0 V$	-	-	90	ns
		$V_{CC} = 4.5 V$	-	-	18	ns
		$V_{CC} = 6.0 V$	-	-	15	ns

[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

[2] t_{en} is the same as t_{PZH} and t_{PZL} .

[3] t_{dis} is the same as t_{PHZ} and t_{PLZ} .

[4] t_t is the same as t_{THL} and t_{TLH} .

[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \sum (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

 $f_i = input frequency in MHz;$

 f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

Table 9. Dynamic characteristics 74HCT366

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; see test circuit Figure 8.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = 2	5 °C						-
t _{pd}	propagation delay	nA to nY; see Figure 6					
		$V_{CC} = 4.5 V$		-	13	24	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	11	-	ns
t _{en}	enable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see Figure 7	[2]	-	16	35	ns
t _{dis}	disable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see Figure 7 [3]		-	20	35	ns
tt	transition time	V _{CC} = 4.5 V; see <u>Figure 6</u>	<u>[4]</u>	-	5	12	ns
C _{PD}	power dissipation capacitance	per buffer; $V_I = GND$ to $(V_{CC} - 1.5 V)$	<u>[5]</u>	-	30	-	pF
T _{amb} = -	40 °C to +85 °C					1	
t _{pd}	propagation delay	nA to nY; V_{CC} = 4.5 V; see <u>Figure 6</u>	<u>[1]</u>	-	-	30	ns
t _{en}	enable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see Figure 7	[2]	-	-	44	ns
t _{dis}	disable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see Figure 7	<u>[3]</u>	-	-	44	ns
t _t	transition time	V_{CC} = 4.5 V; see Figure 6	<u>[4]</u>	-	-	15	ns

Hex buffer/line driver; 3-state; inverting

Table 9. Dynamic characteristics 74HCT366 ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; see test circuit Figure 8.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
•	l0 °C to +125 °C	I		,		
t _{pd}	propagation delay	nA to nY; V_{CC} = 4.5 V; see Figure 6 [1]	-	-	36	ns
t _{en}	enable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see Figure 7 [2]	-	-	53	ns
t _{dis}	disable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see Figure 7 [3]	-	-	53	ns
t _t	transition time	V _{CC} = 4.5 V; see <u>Figure 6</u> [4]	-	-	18	ns

[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

[2] t_{en} is the same as t_{PZH} and t_{PZL} .

[3] t_{dis} is the same as t_{PHZ} and t_{PLZ} .

 $\label{eq:ttime_time} [4] \quad t_t \text{ is the same as } t_{THL} \text{ and } t_{TLH}.$

[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \sum (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

 $f_i = input frequency in MHz;$

 $f_o = output frequency in MHz;$

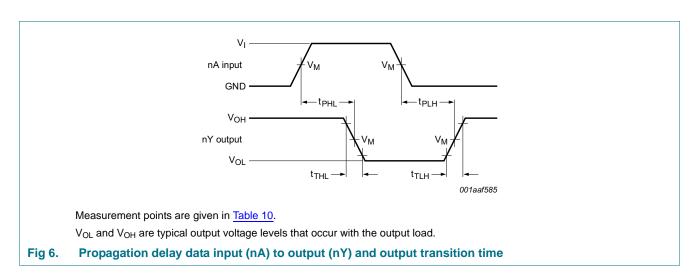
 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o) =$ sum of outputs.

11. Waveforms



Hex buffer/line driver; 3-state; inverting

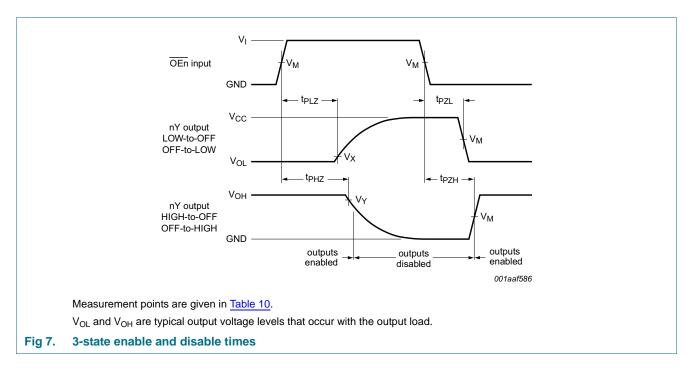


Table 10. Measurement points

Туре	Input	Output		
	V _M	V _M	V _X	V _Y
74HC366	0.5V _{CC}	0.5V _{CC}	$0.1 \times V_{CC}$	$0.9 \times V_{CC}$
74HCT366	1.3 V	1.3 V	$0.1 \times V_{CC}$	$0.9 \times V_{CC}$

74HC_HCT366

Hex buffer/line driver; 3-state; inverting

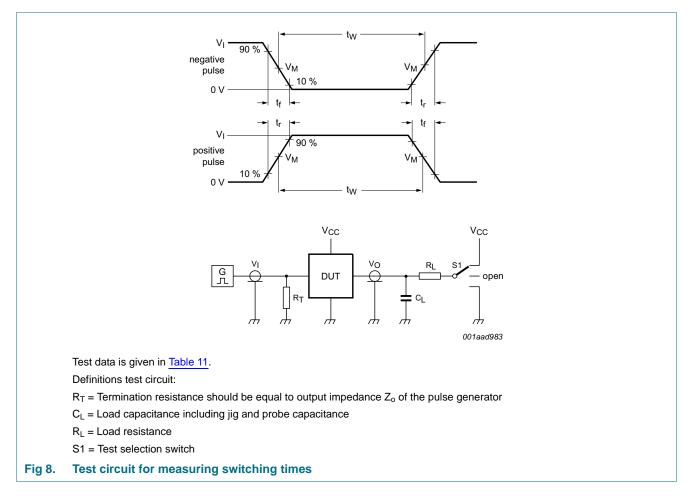


Table 11. Test data

Туре	Input		Load		S1 position		
	VI	t _r , t _f	CL	RL	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
74HC366	V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}
74HCT366	3 V	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}

Hex buffer/line driver; 3-state; inverting

12. Package outline

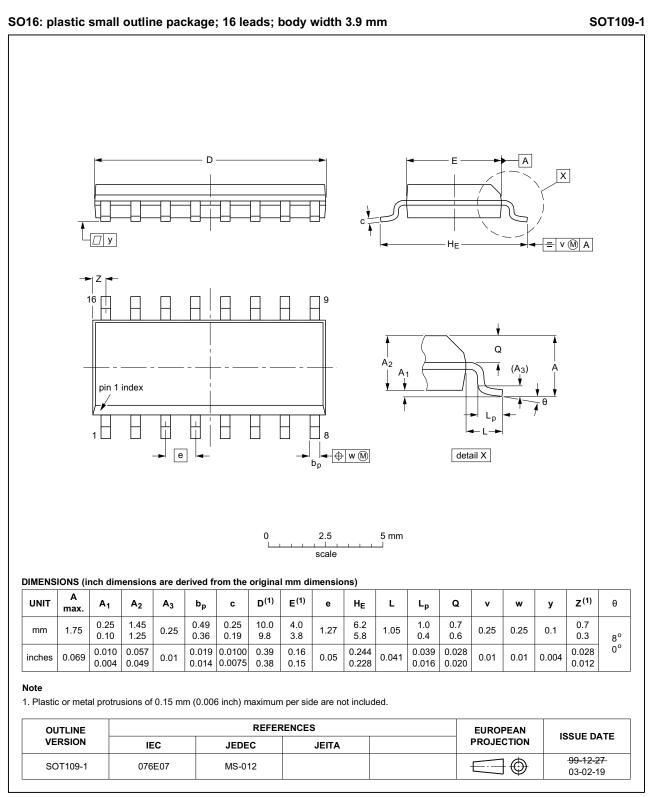


Fig 9. Package outline SOT109-1 (SO16)

74HC_HCT366

Hex buffer/line driver; 3-state; inverting

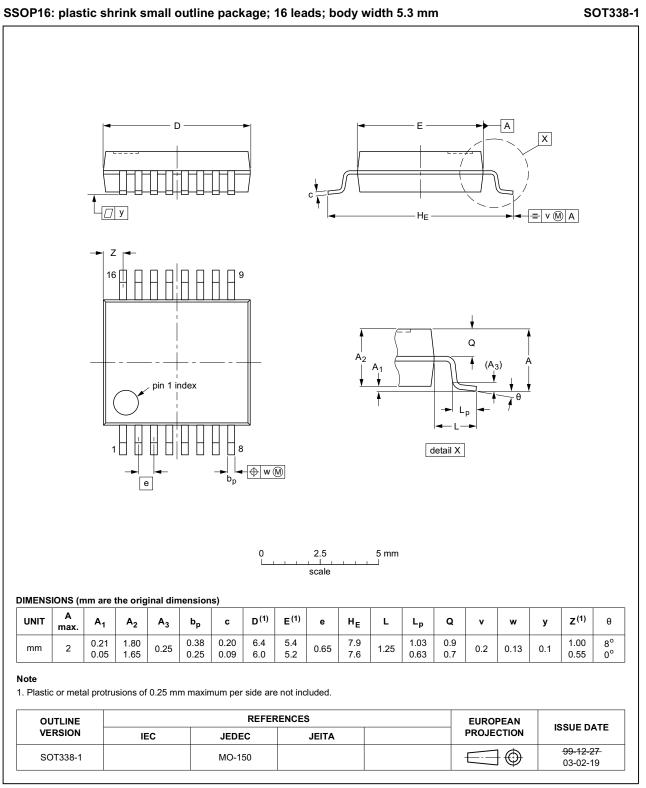


Fig 10. Package outline SOT338-1 (SSOP16)

74HC_HCT366

Hex buffer/line driver; 3-state; inverting

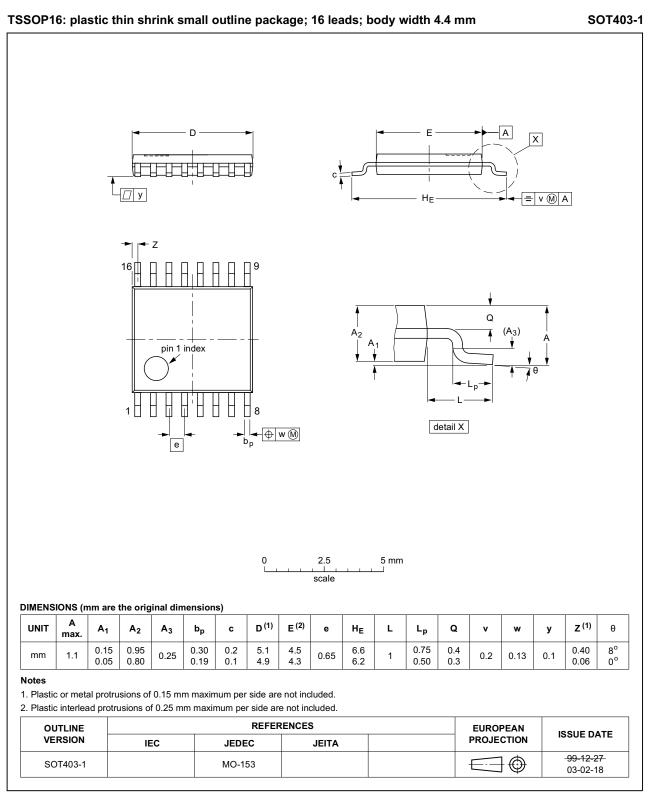


Fig 11. Package outline SOT403-1 (TSSOP16)

74HC_HCT366

Product data sheet

Hex buffer/line driver; 3-state; inverting

13. Abbreviations

Table 12. Abbreviations					
Acronym	Description				
CMOS	Complementary Metal Oxide Semiconductor				
DUT	Device Under Test				
ESD	ElectroStatic Discharge				
HBM	Human Body Model				
MM	Machine Model				

14. Revision history

Table 13.Revision history

Document ID Release date Data sheet status		Data sheet status	Change notice	Supersedes
74HC_HCT366 v.5	20160202	Product data sheet	-	74HC_HCT366 v.4
Modifications:	Type numbers	s 74HC366N and 74HCT366N	(SOT38-4) removed	J.
74HC_HCT366 v.4	20120904	Product data sheet	-	74HC_HCT366 v.3
Modifications:	 Legal pages u 	updated.		
74HC_HCT366 v.3	20061121	Product data sheet	-	74HC_HCT366_CNV v.2
74HC_HCT366_CNV v.2	19901201	Product specification	-	-

Hex buffer/line driver; 3-state; inverting

15. Legal information

15.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

15.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and

customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

15.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of Nexperia.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof. Suitability for use - Nexperia products are not designed,

authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of a Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale - Nexperia

products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nexperia.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Hex buffer/line driver; 3-state; inverting

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific Nexperia product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Nexperia accepts no liability for inclusion and/or use of

non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Nexperia's warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond

16. Contact information

Nexperia's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Nexperia for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Nexperia's standard warranty and Nexperia's product specifications.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

15.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

For more information, please visit: http://www.nexperia.com

For sales office addresses, please send an email to: salesaddresses@nexperia.com

74HC_HCT366

Hex buffer/line driver; 3-state; inverting

17. Contents

1	General description 1
2	Features and benefits 1
3	Ordering information 1
4	Functional diagram 2
5	Pinning information 3
5.1	Pinning
5.2	Pin description 3
6	Functional description 3
7	Limiting values 4
8	Recommended operating conditions 4
9	Static characteristics 5
10	Dynamic characteristics 8
11	Waveforms 11
12	Package outline 14
13	Abbreviations 17
14	Revision history 17
15	Legal information 18
15.1	Data sheet status 18
15.2	Definitions 18
15.3	Disclaimers 18
15.4	Trademarks 19
16	Contact information 19
17	Contents

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Nexperia:

 74HC366D,652
 74HC366D,653
 74HC366N,652
 74HC366PW,112
 74HC366PW,118
 74HCT366D,652

 74HCT366DB,112
 74HCT366DB,118
 74HCT366D,653
 74HCT366N,652
 74HCT366PW,112
 74HCT366PW,112